

Figure 1: NMOS schematic



Figure 2: NMOS simulation window

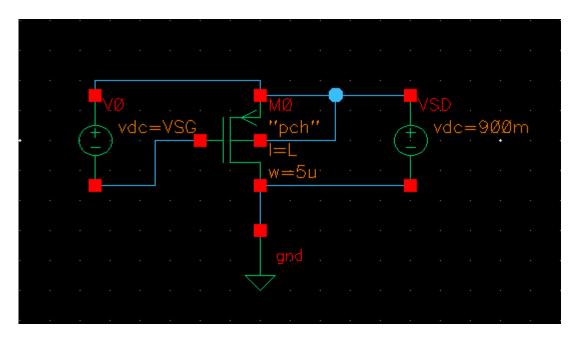


Figure 3: PMOS schematic

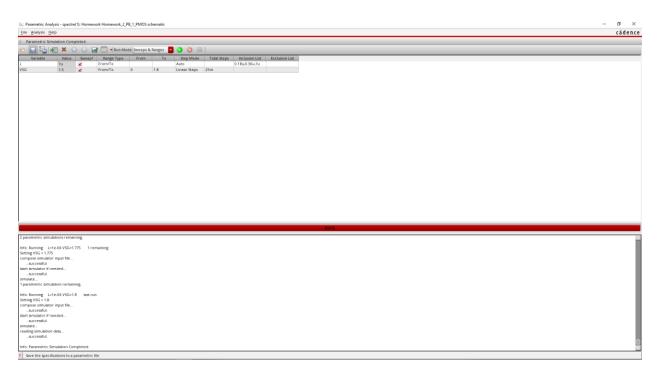
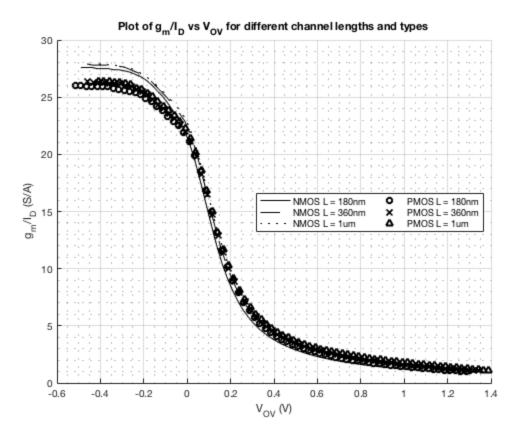


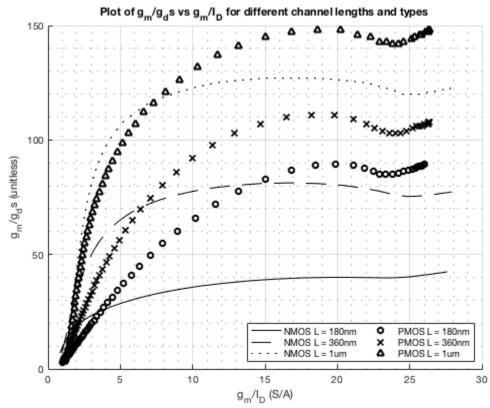
Figure 4: PMOS simulation window

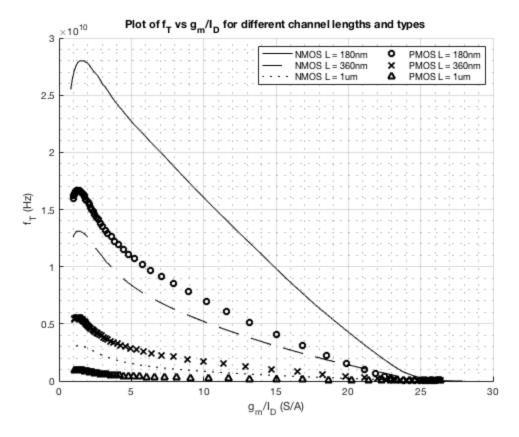
```
%This script reads and plots data from a .CSV file.
clear all;
clc;
%Open data file
fid = fopen('PB1 ALLDATA.csv');
%Read data in from .CSV file
readData = textscan(fid, '%f %f %f %f %f %f %f %f %f %f
 %f', 'Headerlines',2,'Delimiter',',');
%If more columns (yData), add a %f
%NMOS data
Vov 18N = readData\{1,1\}(:,1);
Vov 36N = readData\{1,2\}(:,1);
Vov_1N = readData\{1,3\}(:,1);
gm_over_Id_18N = readData{1,4}(:,1);
gm over Id 36N = readData\{1,5\}(:,1);
gm_over_Id_1N = readData{1,6}(:,1);
gm_over_gds_18N = readData{1,7}(:,1);
gm_over_gds_36N = readData{1,8}(:,1);
gm over gds 1N = readData\{1,9\}(:,1);
ft_18N = readData{1,10}(:,1);
ft_36N = readData\{1,11\}(:,1);
ft_1N = readData\{1,12\}(:,1);
Id over W 18N = readData\{1,13\}(:,1);
Id over W 36N = readData\{1,14\}(:,1);
Id over W 1N = readData\{1,15\}(:,1);
%PMOS Data
Vov 18P = readData{1,16}(:,1);
Vov_36P = readData{1,17}(:,1);
Vov 1P = readData\{1,18\}(:,1);
gm over Id 18P = readData{1,19}(:,1);
gm_over_Id_36P = readData{1,20}(:,1);
gm over Id 1P = readData{1,21}(:,1);
gm over gds 18P = readData\{1,22\}(:,1);
gm_over_gds_36P = readData{1,23}(:,1);
gm_over_gds_1P = readData{1,24}(:,1);
ft 18P = readData\{1,25\}(:,1);
ft 36P = readData\{1,26\}(:,1);
ft_1P = readData{1,27}(:,1);
```

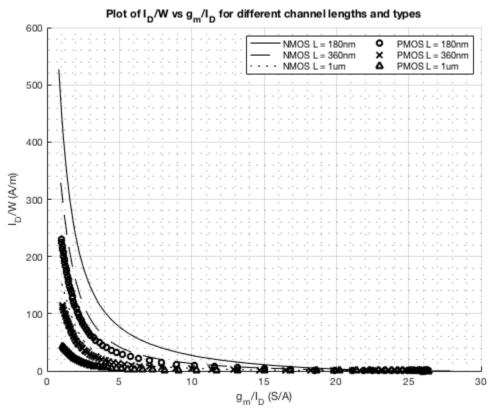
```
Id over W 18P = readData\{1,28\}(:,1);
Id over W 36P = readData\{1,29\}(:,1);
Id over W 1P = readData\{1,30\}(:,1);
%Plot Data
%gm/Id vs Vov
figure(1)
hold on;
plot(Vov_18N, gm_over_Id_18N, 'k-');
plot(Vov 36N, gm over Id 36N, 'k--');
plot(Vov_1N, gm_over_Id_1N, 'k:');
plot(Vov 18P, gm over Id 18P, 'ko');
plot(Vov 36P, gm over Id 36P, 'kx');
plot(Vov 1P, qm over Id 1P, 'k^');
legend('NMOS L = 180nm','NMOS L = 360nm','NMOS L =
 1um', 'PMOS L = 180nm', 'PMOS L = 360nm', 'PMOS L =
 1um', 'Location', 'east', 'NumColumns',2);
title('Plot of g m/I D vs V O V for different channel lengths and
 types');
xlabel('V_0_V (V)');
ylabel('g m/I D (S/A)');
grid on;
grid minor;
%gm/gds vs gm/Id
figure(2)
hold on;
plot(gm over Id 18N, gm over gds 18N, 'k-');
plot(gm_over_Id_36N, gm_over_gds_36N, 'k--');
plot(gm over Id 1N, gm over gds 1N, 'k:');
plot(gm_over_Id_18P, gm_over_gds_18P, 'ko');
plot(gm over Id 36P, gm over gds 36P, 'kx');
plot(gm_over_Id_1P, gm_over_gds_1P, 'k^');
legend('NMOS L = 180nm','NMOS L = 360nm','NMOS L =
 1um', 'PMOS L = 180nm', 'PMOS L = 360nm', 'PMOS L =
 lum', 'Location', 'southeast', 'NumColumns', 2);
title('Plot of g m/g ds vs g m/I D for different channel lengths and
 types');
xlabel('g m/I D (S/A)');
ylabel('g m/g ds (unitless)');
grid on;
grid minor;
%ft vs gm/Id
figure(3)
hold on;
plot(qm over Id 18N, ft 18N, 'k-');
plot(gm over Id 36N, ft 36N, 'k--');
plot(gm_over_Id_1N, ft_1N, 'k:');
plot(gm_over_Id_18P, ft_18P, 'ko');
plot(qm over Id 36P, ft 36P, 'kx');
plot(gm over Id 1P, ft 1P, 'k^');
```

```
legend('NMOS L = 180nm','NMOS L = 360nm','NMOS L =
 1um', 'PMOS L = 180nm', 'PMOS L = 360nm', 'PMOS L =
 lum', 'Location', 'northeast', 'NumColumns',2);
title('Plot of f T vs g m/I D for different channel lengths and
 types');
xlabel('g_m/I_D(S/A)');
ylabel('f T (Hz)');
grid on;
grid minor;
%Id/W vs gm/Id
figure(4)
hold on;
plot(gm over Id 18N, Id over W 18N, 'k-');
plot(gm_over_Id_36N, Id_over W 36N, 'k--');
plot(gm over Id 1N, Id over W 1N, 'k:');
plot(gm_over_Id_18P, Id_over_W_18P, 'ko');
plot(gm over Id 36P, Id over W 36P, 'kx');
plot(gm over Id 1P, Id over W 1P, 'k^');
legend('NMOS L = 180nm','NMOS L = 360nm','NMOS L =
1um', 'PMOS L = 180nm', 'PMOS L = 360nm', 'PMOS L =
lum', 'Location', 'northeast', 'NumColumns',2);
title('Plot of I_D/W vs g_m/I_D for different channel lengths and
 types');
xlabel('g_m/I_D (S/A)');
ylabel('I D/W (A/m)');
grid on;
grid minor;
```











	Simulated gm/Id	Long Channel Estimate	% error
NMOS, L=0.18um, Vov=50mV	18.4079	40	-54%
NMOS, L=0.36um, Vov=50mV	19.5968	40	-51%
NMOS, L=0.36um, Vov=250mV	7.4286	8	-7%
NMOS, L=1um, Vov=250mV	7.8576	8	-2%
PMOS, L=0.18um, Vov=50mV	19.052	40	-52%
PMOS, L=0.36um, Vov=50mV	19.3004	40	-52%
PMOS, L=0.36um, Vov=250mV	7.6539	8	-4%
PMOS, L=1um, Vov=250mV	7.8037	8	-2%

As you can see, the long channel estimate is only appropriate for higher overdrive voltages (Vov).